



## **Small Signal Product**

# **Bi-directional ESD Protection Diode**

### **FEATURES**

- Meet IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- Designed for mounting on small surface
- Protects one Bi-directional I/O line
- Moisture sensitivity level 1
- Working Voltage : 5V, 12V, 24V
- Pb free version and RoHS compliant
- Packing code with suffix "G" means green compound (halogen-free)









Version: F15

### **MECHANICAL DATA**

- Case: 0603 small outline plastic package
- Terminal : Gold plated, solder per MIL-STD-705, method 2026 guaranteed
- High temperature soldering guaranteed : 260°C/10s
- Weight: 3 ± 0.5 mg

### **APPLICATIONS**

- Cell Phone Handsets and Accessories
- Notebooks, Desktops, and Servers
- Keypads, Side Keys, USB 2.0, LCD Displays
- Portable Instrumentation
- Touch Panel

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T <sub>A</sub> =25°C unless otherwise noted)				
PARAMETER		SYMBOL	VALUE	UNIT
Deal Date Deven	TESDU5V0		75	
Peak Pulse Power (tp=8/20µs waveform)	TESDU12V	P <sub>PP</sub>	25	W
(τρ-σ/2ομο wavelofff)	TESDU24V		47	
ESD per IEC 61000-4-2 (Air)		V	± 15	KV
ESD per IEC 61000-4-2 (Contact)		V <sub>ESD</sub>	± 8	- NV
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

PAI	RAMETER		SYMBOL	MIN	MAX	UNIT
	TESDU5V0			-	5	
Reverse Stand-Off Voltage	TESDU12V		$V_{RWM}$	-	12	V
	TESDU24V			-	24	
	TESDU5V0			5.1	-	
Reverse Breakdown Voltage	TESDU12V	$I_R = 1 \text{ mA}$	V <sub>(BR)</sub>	13	-	V
	TESDU24V			25	-	
	TESDU5V0	V <sub>R</sub> = 5 V				
Reverse Leakage Current	TESDU12V	$V_{R} = 12 V$	I <sub>R</sub>	-	2	μΑ
	TESDU24V	$V_R = 24 V$				
Clamping Voltage	TESDUE//0	I <sub>PP</sub> = 1 A	V	-	9.8	V
Clamping Voltage	TESDU5V0 $I_{PP} = 5 A$	V <sub>C</sub>	-	15		
Clamping Voltage	TESDU12V	I <sub>PP</sub> = 1 A	V <sub>C</sub>	-	25	V
Clamping Voltage	16300121	$I_{PP} = 5 A$	V <sub>C</sub>	-	33	v
Clamping Valtage	TESDU24V	I <sub>PP</sub> = 1 A	V <sub>C</sub>	-	47	
Clamping Voltage	1E3D024V	$I_{PP} = 5 A$	V <sub>C</sub>	-	51	V
	TESDU5V0	$V_{R} = 0 V$ $f = 1.0 MHz$		15		
Junction Capacitance	TESDU12V		CJ	12		pF
	TESDU24V				10	

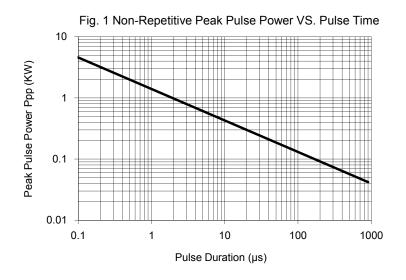
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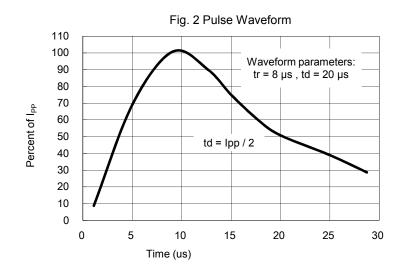


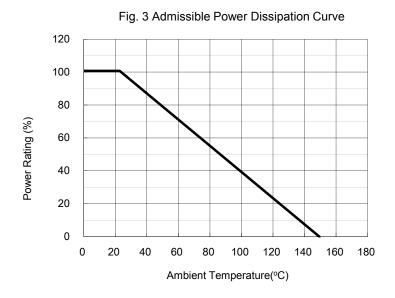
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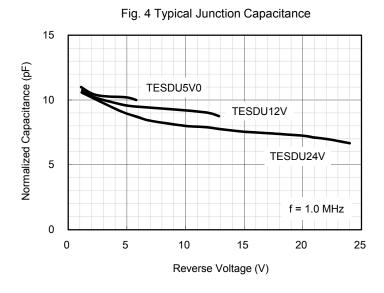
### **RATINGS AND CHARACTERISTICS CURVES**

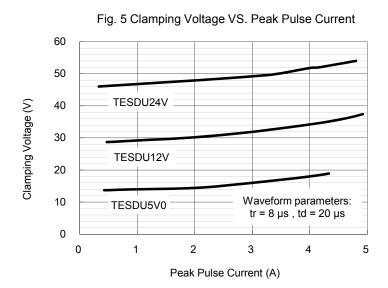
(T<sub>A</sub>=25°C unless otherwise noted)







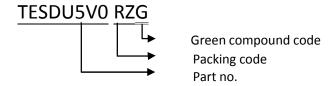




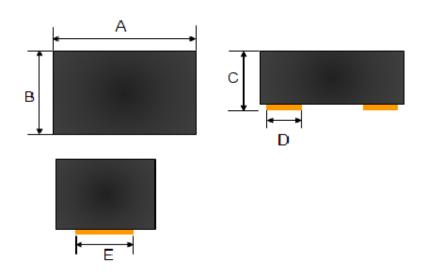


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## **ORDER INFORMATION (EXAMPLE)**

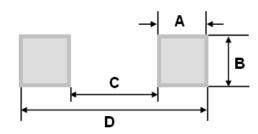


# PACKAGE OUTLINE DIMENSIONS 0603



DIM.	Unit (mm)		Unit (inch)		
DIIVI.	Min	Max	Min	Max	
Α	1.60	1.80	0.063	0.071	
В	0.80	1.00	0.031	0.039	
С	0.70	0.85	0.028	0.033	
D	0.45 (Typ.)		0.018 (Typ.)		
Е	0.70 (Typ.)		0.028	(Typ.)	

## **SUGGEST PAD LAYOUT**



DIM.	Unit (mm)	Unit (inch)	
Dilvi.	Тур.	Тур.	
Α	0.60	0.024	
В	1.00	0.039	
С	0.65	0.026	
D	1.85	0.073	

Note: The suggested land pattern dimensions have been provided for reference only, as actual pad layouts may vary depending on application.

## **MARKING**

Part NO.	Marking
TESDU5V0	E05
TESDU12V	E12
TESDU24V	E24

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## **APPLICATIONS INFORMATION**

- ♦ Designed to protect one data, I/O, or power supply line
- Designed to protect sensitive electronics from damage or latch-up due to ESD
- ♦ Designed to replace multilayer varistors (MLVs) in portable applications
- Features large cross-sectional area junctions for conducting high transient currents
- Offers superior electrical characteristics such as lower clamping voltage and no device degradation when compared to MLVs
- ♦ The combination of small size and high ESD surge capability makes them ideal for use in portable applications

### **CIRCUIT BOARD LAYOUT RECOMMENDATIONS**

Good circuit board layout is critical for the suppression of ESD induced transients

- Place the ESD Protection Diode near the input terminals or connectors to restrict transient coupling
- Minimize the path length between the ESD Protection Diode and the protected line
- ♦ Minimize all conductive loops including power and ground loops
- ♦ The ESD transient return path to ground should be kept as short as possible
- ♦ Never run critical signals near board edges
- ♦ Use ground planes whenever possible

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## TESDU5V0/TESDU12V/TESDU24V



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